

Datasheet V2020.A.1

G3S12010H

1200V/10A Silicon Carbide Power Schottky Barrier Diode

Features

- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

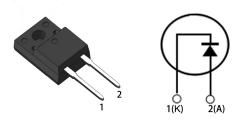
Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements

Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV

Key Characteristics		
V _{RRM}	1200	V
I _{F,} T _c ≤111°C	10	Α
Q _c	54.4	nC





Part No.	Package Type	Marking
G3S12010H	TO-220F	G3S12010H

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}		1200	
Surge Peak Reverse Voltage	V _{RSM}		1200	V
DC Blocking Voltage	V _{DC}		1200	
Continuous Forward		T _C =25℃	16.5	
Current	I _F	Tc=100°C	10	А
Current		T _C =111°C	8.5	
Repetitive Peak Forward	I	$T_c=25^{\circ}C$, tp=10ms, Half Sine	50	А
Surge Current	I _{FRM}	Wave, D=0.3	50	
Non-repetitive Peak	I _{FSM}	$T_{C}\text{=}25^{\circ}\!\!\!^{\circ}\!\!^{\circ}\!\!C$, tp=10ms , Half Sine	140	А
Forward Surge Current	IFSM	Wave	140	
Dower Discination	P _{TOT}	Tc=25℃	54	W
Power Dissipation		Tc =110 ℃	23	W
Operating Junction	Tj		-55℃ to 175℃	$^{\circ}\!$
Storage Temperature	T _{stg}		-55℃ to 175℃	$^{\circ}\mathrm{C}$
NA susting Taxana		M3 Screw	1	Nm
Mounting Torque		6-32 Screw	8.8	lbf-in

Thermal Characteristic

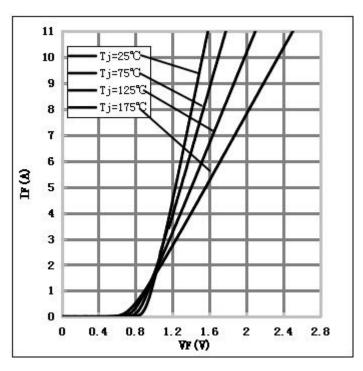
Parameter	Symbol	Test Condition	Value	Unit
Farameter	Symbol	lest condition	Тур.	Unit
Thermal resistance from junction to case	R_{thJC}		2.77	°C/W

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Parameter	Symbol	Test Conditions	Тур.	Max.	Unit	
		$I_F=10A, T_j=25^{\circ}C$	1.55	1.7	V	
Forward Voltage	VF	$I_F=10A, T_j=175$ °C	2.35	2.6	V	
Devenue Comment		$V_R=1200V, T_j=25^{\circ}C$	0.7	50		
Reverse Current	I _R	V _R =1200V, T _j =175 °C	3	100	μΑ	
		V _R =800V, T _j =150°C				
Total Capacitive Charge	Q _C	$Qc = \int_0^{VR} C(V)dV$	54.4	-	nC	
	_	$V_R=0V, T_j=25$ °C, f=1MHZ	765	790		
Total Capacitance	C	V_{R} =400V, T_{j} =25°C, f=1MHZ	50	54	pF	
		V_{R} =800V, T_{j} =25°C, f=1MHZ	48.5	51		

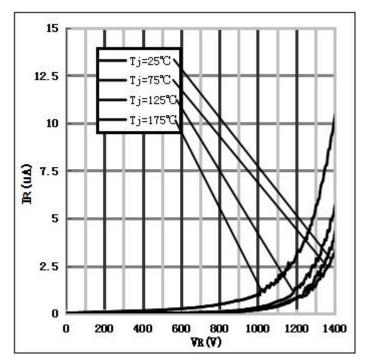
Electrical Characteristics

Performance Graphs

1) Forward IV characteristics as a function of Tj :



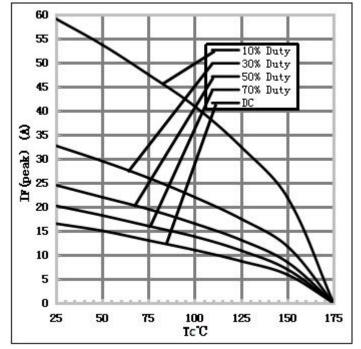
2) Reverse IV characteristics as a function of Tj :

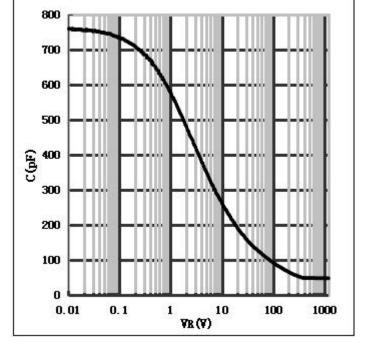


4) Capacitance vs. reverse voltage:

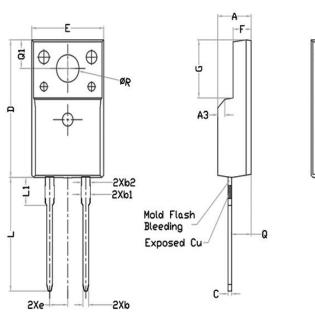
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3) Current Derating:





Package TO-220F



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BOTTOM VIEW

Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash And Burrs Mold Flash Should Be Less Than 6 Mil.

单位	:	mm

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	DIMENSIONS				
SYMBOL	Min.	Nom.	Max.		
A	4.60	4.70	4.80		
b	0.70	0.80	0.91		
b1	1.20	1.30	1.47		
b2	1.10	1.20	1.30		
с	0.45	0.50	0.63		
D	15.80	15.87	15.97		
е		2.54			
Е	10.00	10.10	10.30		
F	2.44	2.54	2.64		
G	6.50	6.70	6.90		
L	12.90	13.10	13.30		
L1	3.13	3.23	3.33		
Q	2.65	2.75	2.85		
Q1	3.20	3.30	3.40		
ΦR	3.08	3.18	3.28		

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: http://globalpowertech.cn/English/index.asp

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